

SN75476 THRU SN75478 DUAL PERIPHERAL DRIVERS

SLRS025A – DECEMBER 1976 – REVISED NOVEMBER 1995

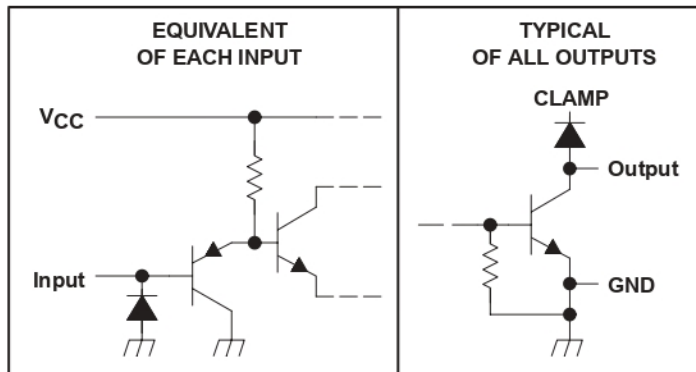
- Characterized for Use to 300 mA
- No Output Latch-Up at 55 V (After Conducting 300 mA)
- High-Voltage Outputs (100 V Typ)
- Output Clamp Diodes for Transient Suppression (300 mA, 70 V)
- TTL- or MOS-Compatible Diode-Clamped Inputs
- pnp Transistor Inputs Reduce Input Current
- Standard Supply Voltage
- Suitable for Hammer-Driver Applications
- Plastic DIP (P) With Copper-Lead Frame Provides Cooler Operation and Improved Reliability

description

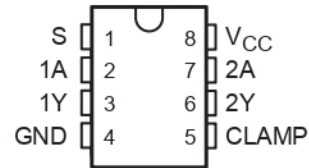
The SN75476 through SN75478 are dual peripheral drivers designed for use in systems that require high current, high voltage, and fast switching times. The SN75476, SN75477, and SN75478 provide AND, NAND, and OR drivers respectively. These devices have diode-clamped inputs as well as high-current, high-voltage clamp diodes on the outputs for inductive transient protection.

The SN75476, SN75477, and SN75478 drivers are characterized for operation from 0°C to 70°C.

schematics of inputs and outputs



D OR P PACKAGE (TOP VIEW)



Function Tables

SN75476
(each AND driver)

INPUTS		OUTPUT
A	S	Y
H	H	H
L	X	L
X	L	L

SN75477
(each NAND driver)

INPUTS		OUTPUT
A	S	Y
H	H	L
L	X	H
X	L	H

SN75478
(each OR driver)

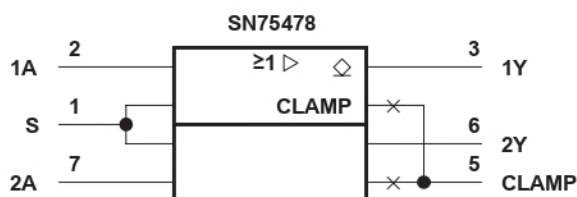
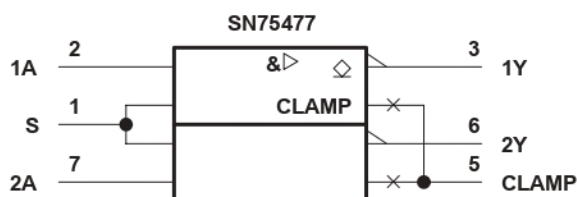
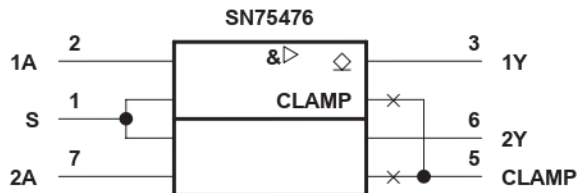
INPUTS		OUTPUT
A	S	Y
H	X	H
X	H	H
L	L	L

H = high level, L = low level
X = irrelevant

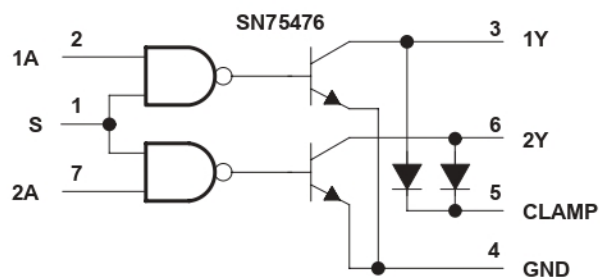
SN75476 THRU SN75478 DUAL PERIPHERAL DRIVERS

SLRS025A – DECEMBER 1976 – REVISED NOVEMBER 1995

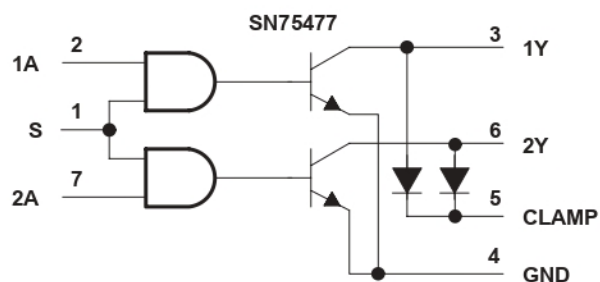
logic symbols†



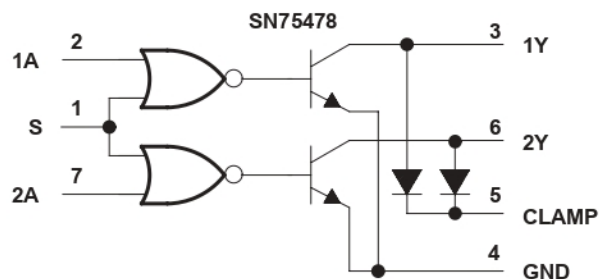
logic diagrams (positive logic)



Positive Logic: $Y = AS$ or $\overline{A+S}$



Positive Logic: $Y = \overline{AS}$ or $\overline{A+S}$



Positive Logic: $Y = A+S$ or $\overline{\overline{A} \overline{S}}$

† These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC publication 617-12.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V_{CC} (see Note 1)	7 V
Input voltage, V_I	5.5 V
Continuous output current (see Note 2)	400 mA
Peak output current: $t_w \leq 10$ ms, duty cycle $\leq 50\%$	500 mA
$t_w \leq 30$ ns, duty cycle $\leq 0.002\%$	3 A
Output clamp current, I_{OK}	400 mA
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T_A	0°C to 70°C
Storage temperature range, T_{stg}	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

- NOTES: 1. Voltage values are with respect to network GND.
2. Both halves of this dual circuit may conduct rated current simultaneously; however, power dissipation averaged over a short time interval must fall within the continuous power dissipation ratings.

DISSIPATION RATING TABLE

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING
D	725 mW	5.8 mW/°C	464 mW
P	1000 mW	8.0 mW/°C	640 mW

recommended operating conditions

	MIN	NOM	MAX	UNIT
Supply voltage, V_{CC}	4.5	5	5.5	V
High-level input voltage, V_{IH}	2			V
Low-level input voltage, V_{IL}			0.8	V
Operating free-air temperature, T_A	0		70	°C



TEXAS
INSTRUMENTS

POST OFFICE BOX 655303 • DALLAS, TEXAS 75265
POST OFFICE BOX 1443 • HOUSTON, TEXAS 77251-1443

SN75476 THRU SN75478 DUAL PERIPHERAL DRIVERS

SLRS025A – DECEMBER 1976 – REVISED NOVEMBER 1995

electrical characteristics over recommended operating free-air temperature range

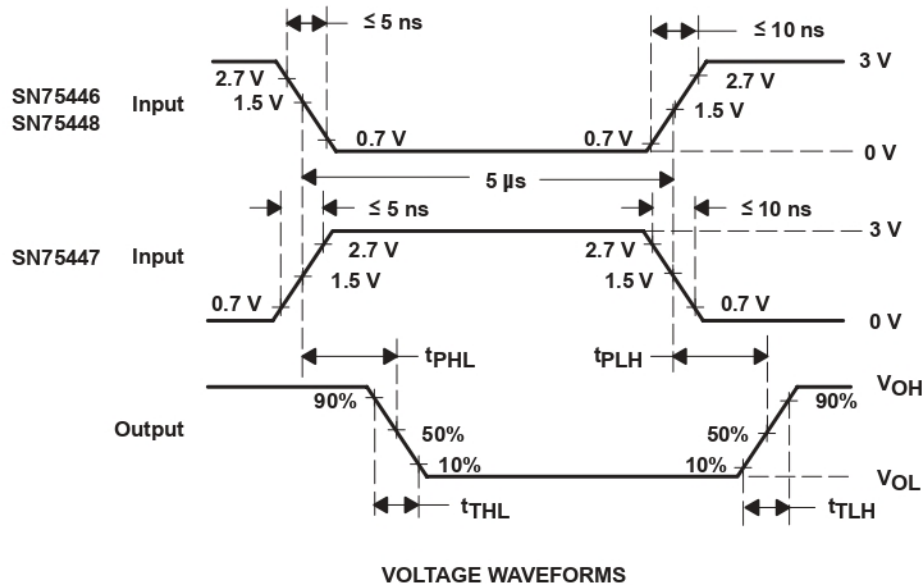
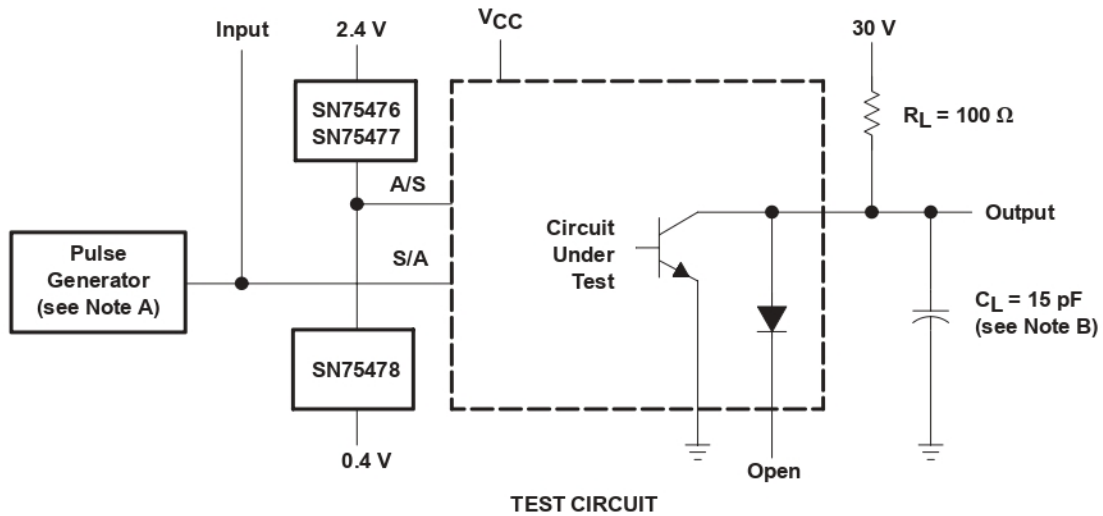
PARAMETER		TEST CONDITIONS		MIN	TYP†	MAX	UNIT
V_{IK}	Input clamp voltage	$I_I = -12 \text{ mA}$		-0.95	-1.5		V
V_{OL}	Low-level output voltage	$V_{CC} = 4.5 \text{ V},$ $V_{IH} = 2 \text{ V},$ $V_{IL} = 0.8 \text{ V}$	$I_{OL} = 100 \text{ mA}$	0.16	0.3		V
			$I_{OL} = 175 \text{ mA}$	0.22	0.5		
			$I_{OL} = 300 \text{ mA}$	0.33	0.6		
$V_{O(BR)}$	Output breakdown voltage	$V_{CC} = 4.5 \text{ V},$	$I_{OH} = 100 \text{ } \mu\text{A}$	70	100		V
$V_{R(K)}$	Output clamp reverse voltage	$V_{CC} = 4.5 \text{ V},$	$I_R = 100 \text{ } \mu\text{A}$	70	100		V
$V_{F(K)}$	Output clamp forward voltage	$V_{CC} = 4.5 \text{ V},$	$I_F = 300 \text{ mA}$	0.8	1.15	1.6	V
I_{OH}	High-level output current	$V_{CC} = 4.5 \text{ V},$ $V_{IL} = 0.8 \text{ V},$	$V_{IH} = 2 \text{ V},$ $V_{OH} = 70 \text{ V}$		1	100	μA
I_{IH}	High-level input current	$V_{CC} = 5.5 \text{ V},$	$V_I = 5.5 \text{ V}$		0.01	10	μA
I_{IL}	Low-level input current	A input	$V_{CC} = 5.5 \text{ V},$ $V_I = 0.8 \text{ V}$	-80	-110		μA
		S input		-160	-220		
I_{CCH}	Supply current, outputs high	SN75476	$V_{CC} = 5.5 \text{ V}$	$V_I = 5 \text{ V}$	10	17	mA
		SN75477		$V_I = 0$	10	17	
		SN75478		$V_I = 5 \text{ V}$	10	17	
I_{CCL}	Supply current, outputs low	SN75476	$V_{CC} = 5.5 \text{ V}$	$V_I = 0$	54	75	mA
		SN75477		$V_I = 5 \text{ V}$	54	75	
		SN75478		$V_I = 0$	54	75	

† All typical values are at $V_{CC} = 5 \text{ V}, T_A = 25^\circ\text{C}$.

switching characteristics, $V_{CC} = 5 \text{ V}, T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
t_{PLH}	Propagation delay time, low-to-high-level output	$C_L = 15 \text{ pF},$ $R_L = 100 \text{ } \Omega,$ See Figure 1			200	350	ns
t_{PHL}	Propagation delay time, high-to-low-level output				200	350	ns
t_{TLH}	Transition time, low-to-high-level output				50	125	ns
t_{THL}	Transition time, high-to-low-level output				90	125	ns
V_{OH}	High-level output voltage after switching	$V_S = 55 \text{ V},$ See Figure 2	$I_O \approx 300 \text{ mA},$	$V_S - 18$			mV

PARAMETER MEASUREMENT INFORMATION



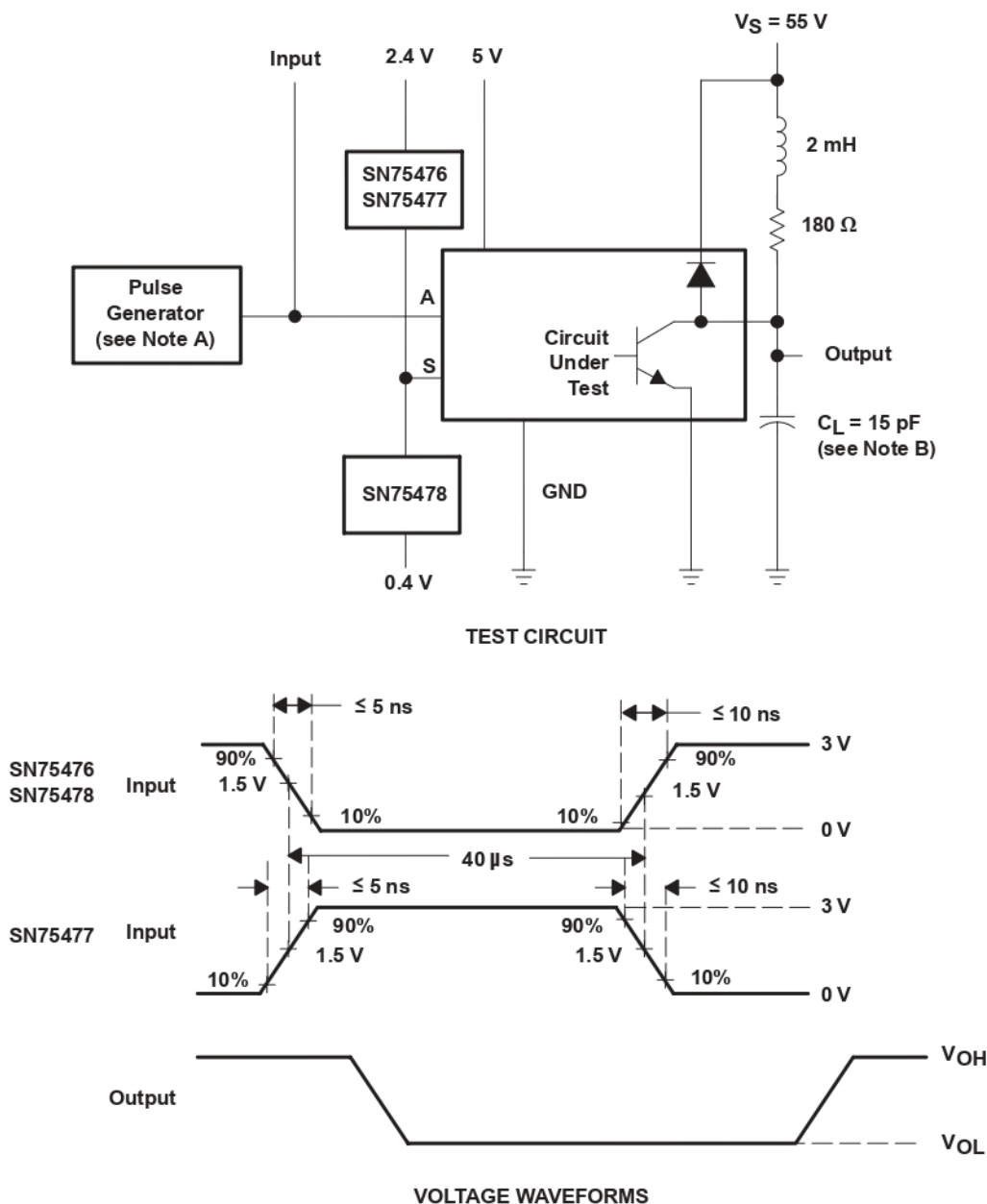
- NOTES: A. The pulse generator has the following characteristics: PRR = 100 kHz, $Z_O = 50 \Omega$
 B. C_L includes probe and jig capacitance.

Figure 1. Test Circuit and Voltage Waveforms, Switching Characteristics

SN75476 THRU SN75478 DUAL PERIPHERAL DRIVERS

SLRS025A – DECEMBER 1976 – REVISED NOVEMBER 1995

PARAMETER MEASUREMENT INFORMATION



- NOTES: A. The pulse generator has the following characteristics: PRR = 12.5 kHz, $Z_O = 50\text{ }\Omega$.
B. C_L includes probe and jig capacitance.

Figure 2. Latch-Up Test Circuit and Voltage Waveforms

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
SN75476D	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI
SN75476DR	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI
SN75476P	OBSOLETE	PDIP	P	8		TBD	Call TI	Call TI
SN75477D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75477DE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75477DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75477DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75477DRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75477DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75477P	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75477PE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75478D	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI
SN75478P	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75478PE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

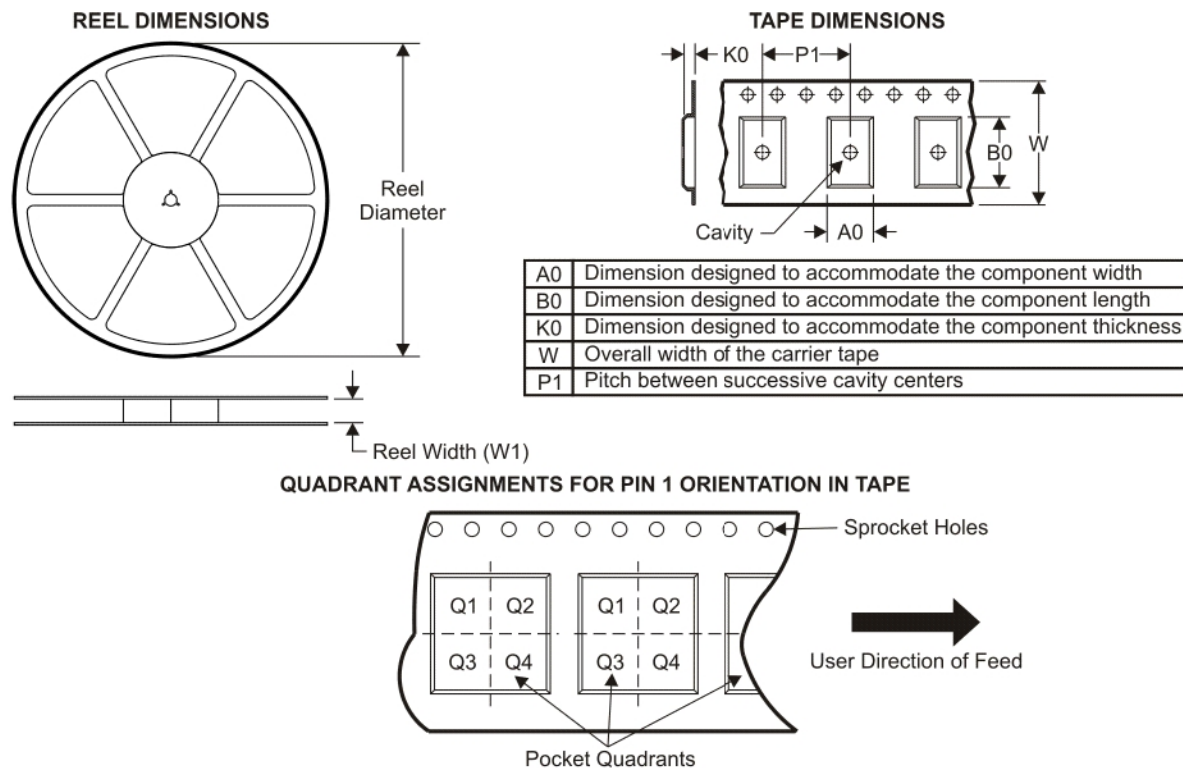
⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited

information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

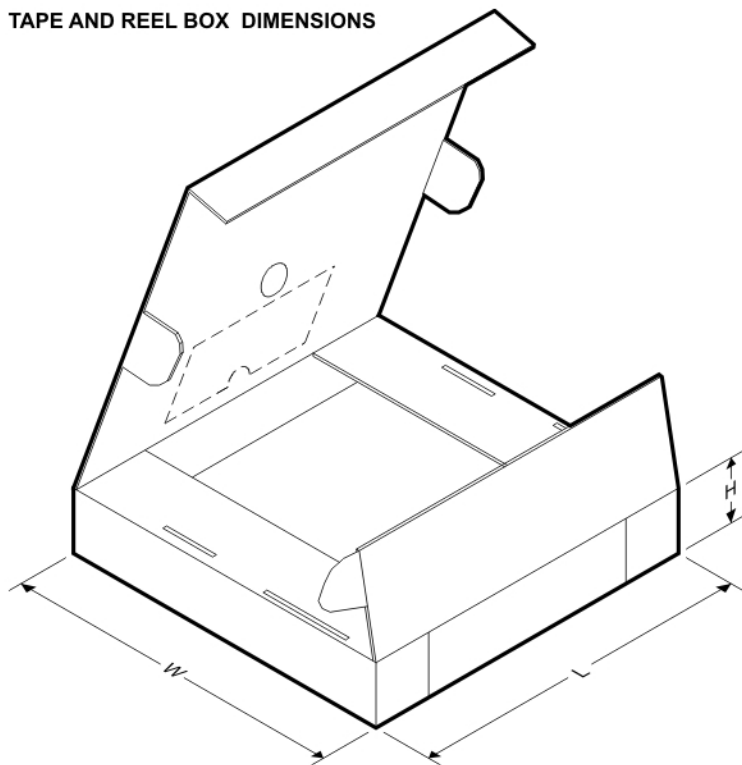
TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN75477DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS

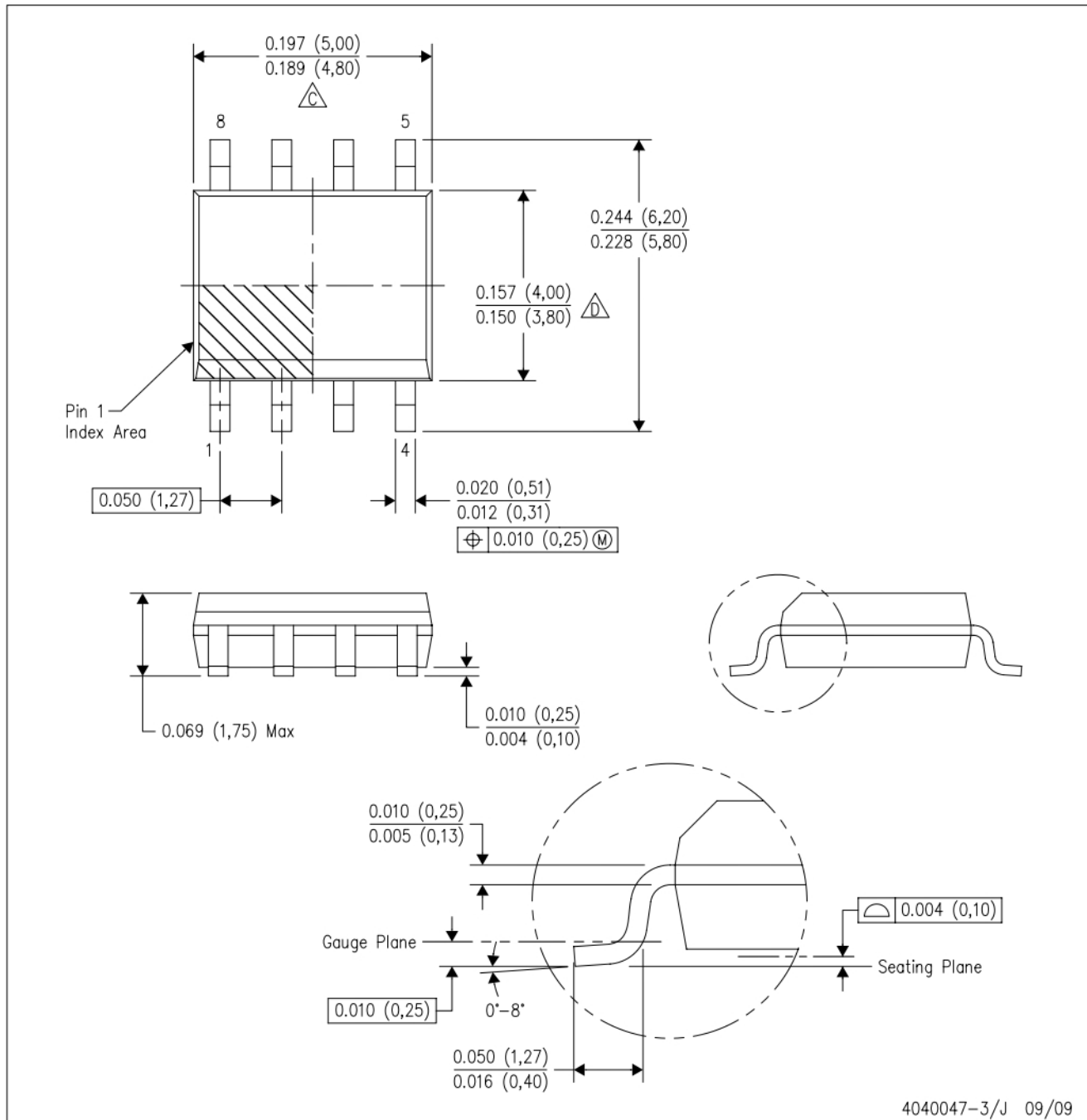


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN75477DR	SOIC	D	8	2500	340.5	338.1	20.6

D (R-PDSO-G8)

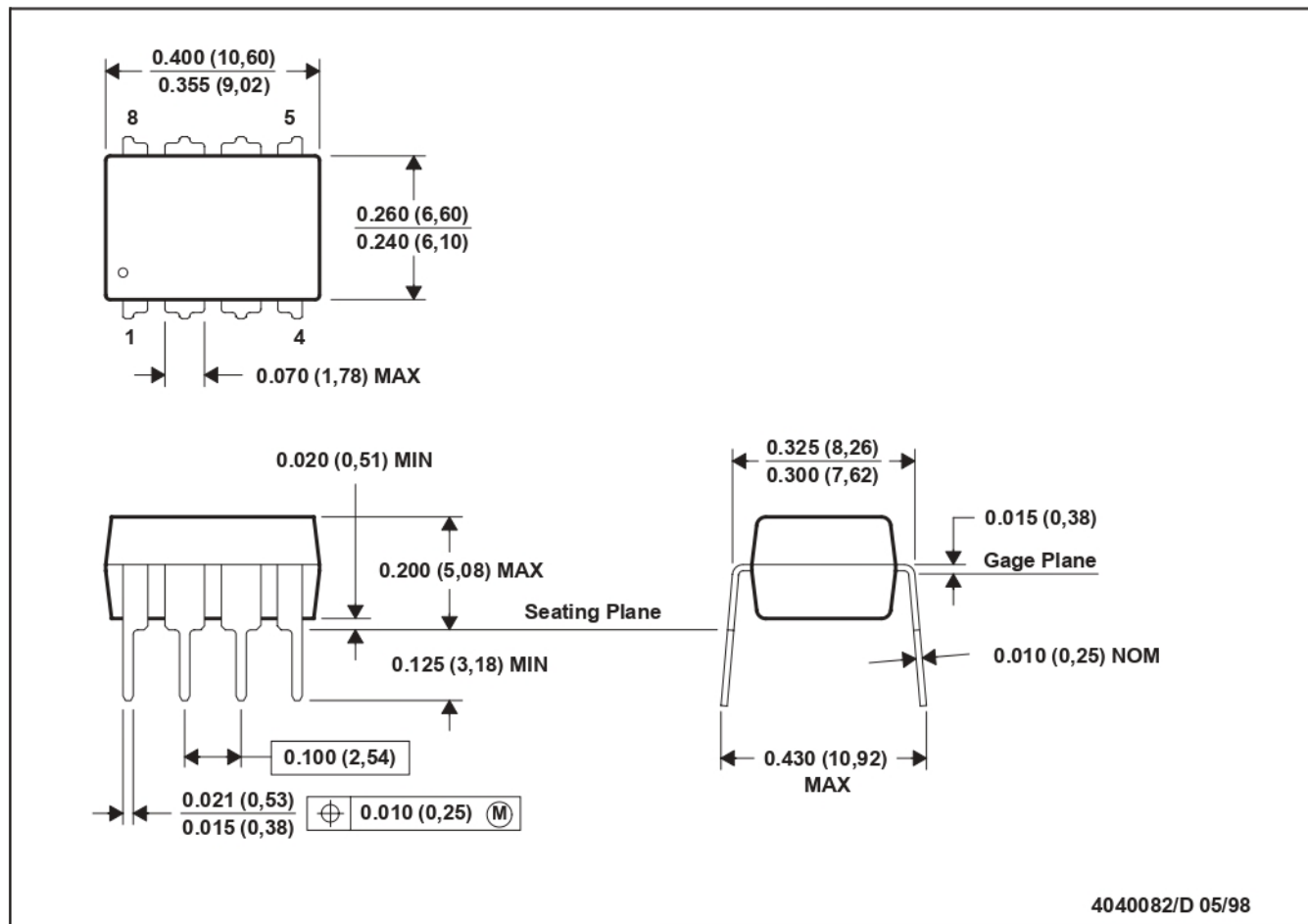
PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - $\triangle C$ Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
 - $\triangle D$ Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
 - E. Reference JEDEC MS-012 variation AA.

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE



- NOTES: A. All linear dimensions are in inches (millimeters).
 B. This drawing is subject to change without notice.
 C. Falls within JEDEC MS-001

For the latest package information, go to http://www.ti.com/sc/docs/package/pkg_info.htm